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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/843,783	04/30/2001	Basanth Jagannathan	FIS920010024US1	1078
32074	7590 04/07/2003			_
INTERNATIONAL BUSINESS MACHINES CORPORATION DEPT. 18G BLDG. 300-482			EXAMINER	
			COLEMAN, WILLIAM D	
2070 ROUTE 52 HOPEWELL JUNCTION, NY 12533 ART UNIT PAPER				PAPER NUMBER
110121121		2823		
	•		DATE MAILED: 04/07/2003	l .

Please find below and/or attached an Office communication concerning this application or proceeding.

			an
		Application N .	Applicant(s)
Office Action Summary		09/843,783	JAGANNATHAN ET AL.
		Examiner	Art Unit
		W. David Coleman	2823
Period f	The MAILING DATE f this communication app or Reply	pears on the cover sheet with th	correspondence address
THE - Extra after - If th - If N - Fail - Any	MAILING DATE OF THIS COMMUNICATION. ensions of time may be available under the provisions of 37 CFR 1.13 or SIX (6) MONTHS from the mailing date of this communication. The period for reply specified above is less than thirty (30) days, a reply operiod for reply is specified above, the maximum statutory period we ure to reply within the set or extended period for reply will, by statute, reply received by the Office later than three months after the mailing ned patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be tily within the statutory minimum of thirty (30) day will apply and will expire SIX (6) MONTHS from Cause the application to become ABANDONE.	mely filed ys will be considered timely. the mailing date of this communication. ED (35 U.S.C. § 133)
1)🛛	Responsive to communication(s) filed on 07 J	lanuary 2003 .	
2a)□	This action is FINAL . 2b)⊠ Thi	is action is non-final.	
3)□		ance except for formal matters, p	rosecution as to the merits is
Disposi	closed in accordance with the practice under a tion of Claims	Ex parte Quayle, 1935 C.D. 11, 4	453 O.G. 213.
4)🖂	Claim(s) 1-15 is/are pending in the application	ı .	
	4a) Of the above claim(s) 10-14 is/are withdraw	n from consideration.	
5)	Claim(s) is/are allowed.		
6)⊠	Claim(s) <u>1-9 and 15</u> is/are rejected.	•	
7)	Claim(s) is/are objected to.		
	Claim(s) are subject to restriction and/or ion Papers	r election requirement.	
9)[The specification is objected to by the Examiner	r.	
10)	The drawing(s) filed on is/are: a) accep	oted or b) objected to by the Exa	miner.
	Applicant may not request that any objection to the	e drawing(s) be held in abeyance. S	ee 37 CFR 1.85(a).
11)	The proposed drawing correction filed on	is: a)☐ approved b)☐ disappro	oved by the Examiner.
_	If approved, corrected drawings are required in rep		
. —	The oath or declaration is objected to by the Exa	aminer.	
Priority	under 35 U.S.C. §§ 119 and 120		
-	Acknowledgment is made of a claim for foreign	priority under 35 U.S.C. § 119(a	a)-(d) or (f).
a)	☐ All b)☐ Some * c)☐ None of:		
	1. Certified copies of the priority documents	s have been received.	
	2. Certified copies of the priority documents	, ,	
* (3.☐ Copies of the certified copies of the prior application from the International Bur See the attached detailed Office action for a list of	reau (PCT Rule 17.2(a)).	•
14) 🔲 /	Acknowledgment is made of a claim for domestic	priority under 35 U.S.C. § 119(e) (to a provisional application).
	a) The translation of the foreign language pro- Acknowledgment is made of a claim for domestic	* *	

U.S. Petent and Trademark Office PTO-326 (Rev. 04-01)

1) Notice of References Cited (PTO-892)

2) Notice of Draftsperson's Patent Drawing Review (PTO-948)

3) Information Disclosure Statement(s) (PTO-1449) Paper No(s)

Attachment(s)

6) Other:

4) Interview Summary (PTO-413) Paper No(s).

5) Notice of Informal Patent Application (PTO-152)

Art Unit: 2823

DETAILED ACTION

Continued Examination Under 37 CFR 1.114

1. A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on January 7, 2003 has been entered.

Claim Rejections - 35 USC § 103

- 2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claims 1-9 and 15 are rejected under 35 U.S.C. 103(a) as being unpatentable over Czubatyj et al., U.S. Patent 5,180,690 in view of Furukawa et al., U.S. Patent 4,885,614.
- 4. Pertaining to claims 1 and 15, <u>Czubatyj</u> discloses a semiconductor process substantially as claimed. <u>Czubatyj</u> teaches Applicants disclosure. Czubatyj discloses a semiconductor process as claimed. Czubatyj teaches a method of reducing film growth rate when growing a carbon-or boron-doped silicon film or silicon-germanium film comprising:

carbon or boron-doping while supplying a silicon precursor (column 11, line 16) and (column 4, line 40) to a substrate, at reduced pressure of about 0.1 to 100 millitor (column 11,

Art Unit: 2823

line 23), at a temperature of below about 800⁰C. (column 5, line 35), wherein said step of doping while supplying includes supplying a dopant precursor from a single source to the substrate. However, Czubatyj does not specifically disclose lowering the flow rate of the silicon precursor, whereby a concentration of the dopant in the substrate increases.

<u>Furukawa</u> teaches a doping concentration as disclosed in Applicants (FIG. 2), i.e., 10¹⁹ cm³(column 4, line 41). In view of <u>Furukawa</u>, it would have been obvious to one of ordinary skill in the art to incorporate the doping concentrations of <u>Furukawa</u> into the <u>Czubatyj</u> semiconductor process because the process will exhibit a high current gain transistor (column 4, lines 61-63).

- 5. Pertaining to claim 2, <u>Czubatyi</u> teaches wherein supplying germanium precursor to the substrate (column 3, line 53).
- 6. Pertaining to claim 4, <u>Czubatyi</u> teaches wherein the doping is at a temperature of less than 8000C (column 7, lines 22-25).
- 7. Pertaining to claim 5, 6 and 7, <u>Czubatyj</u> discloses a semiconductor process substantially as claimed as discussed above. However, <u>Czubatyj</u> fails to disclose wherein the dopant is carbon and wherein the carbon doping is by a carbon precursor supply that is a single source. <u>Furukawa</u> teaches a single source carbon doping gas (Example 6). In view of <u>Furukawa</u>, it would have been obvious to one of ordinary skill in the art to incorporate a single source carbon doping gas into the <u>Czubatyj</u> semiconductor process because the process forms a doped silicon-germanium-carbon layer simultaneously (column 9, lines 45-49).
- 8. Pertaining to claims 3, 8 and 9 the combined teaches fail to disclose the ranges as claimed for the process of reducing film growth rate when growing carbon or boron-doped silicon film or

⁴ Application/Control Number: 09/843,783

Art Unit: 2823

silicon-germanium film. Given the teaching of the references, it would have been obvious to determine the optimum thickness, temperature as well as condition of delivery of the layers involved. See *In re Aller, Lacey and Hall* (10 USPQ 233-237) "It is not inventive to discover optimum or workable ranges by routine experimentation. Note that the specification contains no disclosure of either the critical nature of the claimed ranges or any unexpected results arising therefrom. Where patentability is said to be based upon particular chosen dimensions or upon another variable recited in a claim, the Applicant must show that the chosen dimensions are critical. *In re Woodruff*, 919 f.2d 1575, 1578, 16 USPQ2d 1934, 1936 (Fed. Cir. 1990).

Any differences in the claimed invention and the prior art may be expected to result in some differences in properties. The issue is whether the properties differ to such an extent that the difference is really unexpected. *In re Merck & Co.*, 800 F.2d 1091, 231 USPQ 375 (Fed. Cir. 1986)

Appellants have the burden of explaining the data in any declaration they proffer as evidence of non-obviousness. *Ex parte Ishizaka*, 24 USPQ2d 1621, 1624 (Bd. Pat. App. & Inter. 1992).

An Affidavit or declaration under 37 CFR 1.132 must compare the claimed subject matter with the closest prior art to be effective to rebut a prima facie case of obviousness. *In re Burckel*, 592 F.2d 1175, 201 USPQ 67 (CCPA 1979).

Conclusion

9. Any inquiry concerning this communication or earlier communications from the examiner should be directed to W. David Coleman whose telephone number is 703-305-0004. The examiner can normally be reached on 9:00 AM-5:00 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Olik Chaudhuri can be reached on 703-306-2794. The fax phone numbers for the

Art Unit: 2823

organization where this application or proceeding is assigned are 703-308-7722 for regular communications and 703-308-7721 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

W. David Coleman

Examiner Art Unit 2823

WDC April 2, 2003